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Features

- Incorporates the ARM7TDMI® ARM® Thumb® Processor
 - High-performance 32-bit RISC Architecture
 - High-density 16-bit Instruction Set
 - Leader in MIPS/Watt
 - EmbeddedlCE[™] In-circuit Emulation, Debug Communication Channel Support
- · Internal High-speed Flash
 - 512 Kbytes (AT91SAM7XC512) Organized in Two Banks of 1024 Pages of 256 Bytes (Dual Plane)
 - 256 Kbytes (AT91SAM7XC256) Organized in 1024 Pages of 256 Bytes (Single Plane)
 - 128 Kbytes (AT91SAM7XC128) Organized in 512 Pages of 256 Bytes (Single Plane)
 - Single Cycle Access at Up to 30 MHz in Worst Case Conditions
 - Prefetch Buffer Optimizing Thumb Instruction Execution at Maximum Speed
 - Page Programming Time: 6 ms, Including Page Auto-erase,
 Full Erase Time: 15 ms
 - 10,000 Write Cycles, 10-year Data Retention Capability, Sector Lock Capabilities, Flash Security Bit
 - Fast Flash Programming Interface for High Volume Production
- Internal High-speed SRAM, Single-cycle Access at Maximum Speed
 - 128 Kbytes (AT91SAM7XC512)
 - 64 Kbytes (AT91SAM7XC256)
 - 32 Kbytes (AT91SAM7XC128)
- Memory Controller (MC)
 - Embedded Flash Controller, Abort Status and Misalignment Detection
- Reset Controller (RSTC)
 - Based on Power-on Reset Cells and Low-power Factory-calibrated Brownout Detector
 - Provides External Reset Signal Shaping and Reset Source Status
- Clock Generator (CKGR)
 - Low-power RC Oscillator, 3 to 20 MHz On-chip Oscillator and one PLL
- Power Management Controller (PMC)
 - Power Optimization Capabilities, Including Slow Clock Mode (Down to 500 Hz) and Idle Mode
 - Four Programmable External Clock Signals
- Advanced Interrupt Controller (AIC)
 - Individually Maskable, Eight-level Priority, Vectored Interrupt Sources
 - Two External Interrupt Sources and One Fast Interrupt Source, Spurious Interrupt Protected
- Debug Unit (DBGU)
 - 2-wire UART and Support for Debug Communication Channel interrupt,
 Programmable ICE Access Prevention
 - Mode for General Purpose 2-wire UART Serial Communication
- Periodic Interval Timer (PIT)
 - 20-bit Programmable Counter plus 12-bit Interval Counter
- Windowed Watchdog (WDT)
 - 12-bit Key-protected Programmable Counter
 - Provides Reset or Interrupt Signals to the System
 - Counter May Be Stopped While the Processor is in Debug State or in Idle Mode



Product Description

AT91SAM7XC512 AT91SAM7XC258 AT91SAM7XC128

Summary

NOTE: This is a summary document. The complete document is available on the Atmel website at www.atmel.com.

6209DS-ATARM-17-Feb-09





- Real-time Timer (RTT)
 - 32-bit Free-running Counter with Alarm
 - Runs Off the Internal RC Oscillator
- Two Parallel Input/Output Controllers (PIO)
 - Sixty-two Programmable I/O Lines Multiplexed with up to Two Peripheral I/Os
 - Input Change Interrupt Capability on Each I/O Line
 - Individually Programmable Open-drain, Pull-up Resistor and Synchronous Output
- Seventeen Peripheral DMA Controller (PDC) Channels
- One Advanced Encryption System (AES)
 - 256-, 192-, 128-bit Key Algorithm, Compliant with FIPS PUB 197 Specifications (AT91SAM7XC512)
 - 128-bit Key Algorithm, Compliant with FIPS PUB 197 Specifications (AT91SAM7XC256/128)
 - Buffer Encryption/Decryption Capabilities with PDC
- One Triple Data Encryption System (TDES)
 - Two-key or Three-key Algorithms, Compliant with FIPS PUB 46-3 Specifications
 - Optimized for Triple Data Encryption Capability
- One USB 2.0 Full Speed (12 Mbits per second) Device Port
 - On-chip Transceiver, 1352-byte Configurable Integrated FIFOs
- One Ethernet MAC 10/100 base-T
 - Media Independent Interface (MII) or Reduced Media Independent Interface (RMII)
 - Integrated 28-byte FIFOs and Dedicated DMA Channels for Transmit and Receive
- One Part 2.0A and Part 2.0B Compliant CAN Controller
 - Eight Fully-programmable Message Object Mailboxes, 16-bit Time Stamp Counter
- One Synchronous Serial Controller (SSC)
 - Independent Clock and Frame Sync Signals for Each Receiver and Transmitter
 - I²S Analog Interface Support, Time Division Multiplex Support
 - High-speed Continuous Data Stream Capabilities with 32-bit Data Transfer
- Two Universal Synchronous/Asynchronous Receiver Transmitters (USART)
 - Individual Baud Rate Generator, IrDA Infrared Modulation/Demodulation
 - Support for ISO7816 T0/T1 Smart Card, Hardware Handshaking, RS485 Support
 - Full Modem Line Support on USART1
- Two Master/Slave Serial Peripheral Interfaces (SPI)
 - 8- to 16-bit Programmable Data Length, Four External Peripheral Chip Selects
- One Three-channel 16-bit Timer/Counter (TC)
 - Three External Clock Inputs, Two Multi-purpose I/O Pins per Channel
 - Double PWM Generation, Capture/Waveform Mode, Up/Down Capability
- One Four-channel 16-bit Power Width Modulation Controller (PWMC)
- One Two-wire Interface (TWI)
 - Master Mode Support Only, All Two-wire Atmel EEPROMs and I²C Compatible Devices Supported
- One 8-channel 10-bit Analog-to-Digital Converter, Four Channels Multiplexed with Digital I/Os
- SAM-BA[™] Boot Assistant
 - Default Boot program
 - Interface with SAM-BA Graphic User Interface
- IEEE 1149.1 JTAG Boundary Scan on All Digital Pins
- 5V-tolerant I/Os, Including Four High-current Drive I/O lines, Up to 16 mA Each
- Power Supplies
 - Embedded 1.8V Regulator, Drawing up to 100 mA for the Core and External Components
 - 3.3V VDDIO I/O Lines Power Supply, Independent 3.3V VDDFLASH Flash Power Supply
 - 1.8V VDDCORE Core Power Supply with Brownout Detector

AT91SAM7XC512/256/128

- Fully Static Operation: Up to 55 MHz at 1.65V and 85 C Worst Case Conditions
- Available in 100-lead LQFP Green and 100-ball TFBGA Green Packages





1. Description

Atmel's AT91SAM7XC512/256/128 is a member of a series of highly integrated Flash microcontrollers based on the 32-bit ARM RISC processor. It features 512/256/128 Kbyte high-speed Flash and 128/64/32 Kbyte SRAM, a large set of peripherals, including an 802.3 Ethernet MAC, a CAN controller, an AES 128 Encryption accelerator and a Triple Data Encryption System. A complete set of system functions minimizes the number of external components.

The embedded Flash memory can be programmed in-system via the JTAG-ICE interface or via a parallel interface on a production programmer prior to mounting. Built-in lock bits and a security bit protect the firmware from accidental overwrite and preserve its confidentiality.

The AT91SAM7XC512/256/128 system controller includes a reset controller capable of managing the power-on sequence of the microcontroller and the complete system. Correct device operation can be monitored by a built-in brownout detector and a watchdog running off an integrated RC oscillator.

By combining the ARM7TDMI processor with on-chip Flash and SRAM, and a wide range of peripheral functions, including USART, SPI, CAN Controller, Ethernet MAC, AES 128 accelerator, TDES, Timer Counter, RTT and Analog-to-Digital Converters on a monolithic chip, the AT91SAM7XC512/256/128 is a powerful device that provides a flexible, cost-effective solution to many embedded control applications requiring secure communication over, for example, Ethernet, CAN wired and Zigbee[™] wireless networks.

1.1 Configuration Summary of the AT91SAM7XC512/256/128

The AT91SAM7XC512, AT91SAM7XC256 and AT91SAM7XC128 differ only in memory sizes. Table 1-1 summarizes the configurations of the two devices.

Table 1-1. Configuration Summary

Device	Flash	Flash Organization	SRAM	AES	TDES
AT91SAM7XC512	512K bytes	dual plane	128K bytes	1 AES 256/192/128	1
AT91SAM7XC256	256K bytes	single plane	64K bytes	1 AES 128	1
AT91SAM7XC128	128K bytes	single plane	32K bytes	1 AES 128	1

2. AT91SAM7XC512/256/128 Block Diagram

TDI TDO TMS TCK ICE ARM7TDMI SCAN Processor JTAGSEL 1.8 V VDDIN Voltage GND System Controller Regulato VDDOUT TST FIQ VDDCORE AIC - VDDIO Memory Controller SRAM Embedded Address 128/64/32 PDC DRXD Decoder Kbytes DBGU Controlle DTXD PDC Abort Misalignmen PCK0-PCK3 Status Detection VDDFLASH PLLRC PLL Flash ERASE 512/256/128 PMC osc XOUT -Kbytes Peripheral Bridge RCOSC Peripheral DMA ROM BOD **VDDFLASH** Controller PGMRDY PGMRDY
PGMNVALID
PGMNOE
PGMCK
PGMM0-PGMM3
PGMD0-PGMD15
PGMNCMD
PGMEN0-PGMEN1 Reset 17 Channels Fast Flash POR VDDCORE Controller Programming Interface NRST PIT APB SAM-BA WDT RTT ETXCK-ERXCK-EREFCK
ETXEN-ETXER
ECRS-ECOL, ECRSDV
ERXER-ERXDV
ERXO-ERX3
ETX0-ETX3
EMDIC
EMDIO
EF100 DMA Ethernet MAC 10/100 PDC TXD0 SCK0 RTS0 USART0 PDC PDC CTS0 RXD1 TXD1 SCK1 RTS1 CTS1 DCD1 DSR1 DTR1 RI1 VDDFLASH FIFO DDM USB Device USART1 PWM0 PWM1 PWM2 PWM3 TF TK TD RD RK RF PDC **PWMC** SPIO_NPCS1
SPIO_NPCS2
SPIO_NPCS3
SPIO_MISO
SPIO_MOSI
SPIO_SPCK PDC PDC SPI0 SSC PDC SPI1_NPCS0 SPI1_NPCS1 SPI1_NPCS2 SPI1_NPCS3 SPI1_MISO SPI1_MOSI SPI1_SPCK PDC TCLK0 TCLK1 TCLK2 TIOA0 TIOB0 Timer Counter SPI1 TC0 PDC PDC TIOA1 TIOB1 TC1 ADTRG AD0 AD1 AD2 AD3 TIOA2 TIOB2 TC2 TWD TWCK TWI ADC AD4 AD5 AD6 AD7 CAN PDC ADVREF **AES 128** PDC PDC TDES PDC

Figure 2-1. AT91SAM7XC512/256/128 Block Diagram





3. Signal Description

 Table 3-1.
 Signal Description List

Signal Name	Function	Туре	Active Level	Comments
	Po	wer		
VDDIN	Voltage Regulator and ADC Power Supply Input	Power		3V to 3.6V
VDDOUT	Voltage Regulator Output	Power		1.85V
VDDFLASH	Flash and USB Power Supply	Power		3V to 3.6V
VDDIO	I/O Lines Power Supply	Power		3V to 3.6V
VDDCORE	Core Power Supply	Power		1.65V to 1.95V
VDDPLL	PLL	Power		1.65V to 1.95V
GND	Ground	Ground		
	Clocks, Oscilla	ators and PLLs		
XIN	Main Oscillator Input	Input		
XOUT	Main Oscillator Output	Output		
PLLRC	PLL Filter	Input		
PCK0 - PCK3	Programmable Clock Output	Output		
	ICE an	d JTAG		
тск	Test Clock	Input		No pull-up resistor
TDI	Test Data In	Input		No pull-up resistor
TDO	Test Data Out	Output		
TMS	Test Mode Select	Input		No pull-up resistor
JTAGSEL	JTAG Selection	Input		Pull-down resistor ⁽¹⁾
	Flash I	Memory	1	
ERASE	Flash and NVM Configuration Bits Erase Command	Input	High	Pull-down resistor ⁽¹⁾
	Rese	t/Test	1	
NRST	Microcontroller Reset	I/O	Low	Pull-Up resistor, Open Drain Output.
TST	Test Mode Select	Input	High	Pull-down resistor ⁽¹⁾
	Debu	g Unit	1	
DRXD	Debug Receive Data	Input		
DTXD	Debug Transmit Data	Output		
	A	IC	1	
IRQ0 - IRQ1	External Interrupt Inputs	Input		
FIQ	Fast Interrupt Input	Input		
	Р	10		•
PA0 - PA30	Parallel IO Controller A	I/O		Pulled-up input at reset.
PB0 - PB30	Parallel IO Controller B	I/O		Pulled-up input at reset.

 Table 3-1.
 Signal Description List (Continued)

Signal Name	Function	Туре	Active Level	Comments
· ·	USB De	vice Port		
DDM	USB Device Port Data -	Analog		
DDP	USB Device Port Data +	Analog		
	US	ART		
SCK0 - SCK1	Serial Clock	I/O		
TXD0 - TXD1	Transmit Data	I/O		
RXD0 - RXD1	Receive Data	Input		
RTS0 - RTS1	Request To Send	Output		
CTS0 - CTS1	Clear To Send	Input		
DCD1	Data Carrier Detect	Input		
DTR1	Data Terminal Ready	Output		
DSR1	Data Set Ready	Input		
RI1	Ring Indicator	Input		
	Synchronous	Serial Controller		
TD	Transmit Data	Output		
RD	Receive Data	Input		
TK	Transmit Clock	I/O		
RK	Receive Clock	I/O		
TF	Transmit Frame Sync	I/O		
RF	Receive Frame Sync	I/O		
	Timer/	Counter	1	
TCLK0 - TCLK2	External Clock Inputs	Input		
TIOA0 - TIOA2	I/O Line A	I/O		
TIOB0 - TIOB2	I/O Line B	I/O		
	PWM C	ontroller		
PWM0 - PWM3	PWM Channels	Output		
	Serial Periphera	al Interface - SPI	x	
SPIx_MISO	Master In Slave Out	I/O		
SPIx_MOSI	Master Out Slave In	I/O		
SPIx_SPCK	SPI Serial Clock	I/O		
SPIx_NPCS0	SPI Peripheral Chip Select 0	I/O	Low	
SPIx_NPCS1-NPCS3	SPI Peripheral Chip Select 1 to 3	Output	Low	
	Two-wire	e Interface	•	
TWD	Two-wire Serial Data	I/O		
TWCK	Two-wire Serial Clock	I/O		





 Table 3-1.
 Signal Description List (Continued)

Signal Name	Function	Туре	Active Level	Comments		
Analog-to-Digital Converter						
AD0-AD3	Analog Inputs	Analog		Digital pulled-up inputs at reset.		
AD4-AD7	Analog Inputs	Analog		Analog Inputs		
ADTRG	ADC Trigger	Input				
ADVREF	ADC Reference	Analog				
	Fast Flash Prog	ramming Interfac	е			
PGMEN0-PGMEN1	Programming Enabling	Input				
PGMM0-PGMM3	Programming Mode	Input				
PGMD0-PGMD15	Programming Data	I/O				
PGMRDY	Programming Ready	Output	High			
PGMNVALID	Data Direction	Output	Low			
PGMNOE	Programming Read	Input	Low			
PGMCK	Programming Clock	Input				
PGMNCMD	Programming Command	Input	Low			
	CAN	Controller				
CANRX	CAN Input	Input				
CANTX	CAN Output	Output				
	Ethernet	MAC 10/100	l			
EREFCK	Reference Clock	Input		RMII only		
ETXCK	Transmit Clock	Input		MII only		
ERXCK	Receive Clock	Input		MII only		
ETXEN	Transmit Enable	Output				
ETX0 - ETX3	Transmit Data	Output		ETX0 - ETX1 only in RMII		
ETXER	Transmit Coding Error	Output		MII only		
ERXDV	Receive Data Valid	Input		MII only		
ECRSDV	Carrier Sense and Data Valid	Input		RMII only		
ERX0 - ERX3	Receive Data	Input		ERX0 - ERX1 only in RMII		
ERXER	Receive Error	Input				
ECRS	Carrier Sense	Input		MII only		
ECOL	Collision Detected	Input		MII only		
EMDC	Management Data Clock	Output				
EMDIO	Management Data Input/Output	I/O				
EF100	Force 100 Mbits/sec.	Output	High	RMII only		

Note: 1. Refer to Section 6. "I/O Lines Considerations".

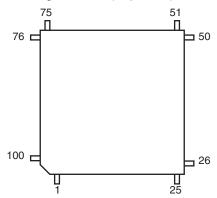
4. Package

The AT91SAM7XC512/256/128 is available in 100-lead LQFP Green and 100-ball TFBGA RoHS-compliant packages.

4.1 100-lead LQFP Package Outline

Figure 4-1 shows the orientation of the 100-lead LQFP package. A detailed mechanical description is given in the Mechanical Characteristics section of the full datasheet.

Figure 4-1. 100-lead LQFP Package Outline (Top View)







4.2 100-lead LQFP Pinout

Table 4-1.Pinout in 100-lead LQFP Package

1	ADVREF
2	GND
3	AD4
4	AD5
5	AD6
6	AD7
7	VDDOUT
8	VDDIN
9	PB27/AD0
10	PB28/AD1
11	PB29/AD2
12	PB30/AD3
13	PA8/PGMM0
14	PA9/PGMM1
15	VDDCORE
16	GND
17	VDDIO
18	PA10/PGMM2
19	PA11/PGMM3
20	PA12/PGMD0
21	PA13/PGMD1
22	PA14/PGMD2
23	PA15/PGMD3
24	PA16/PGMD4
25	PA17/PGMD5

26	PA18/PGMD6
27	PB9
	. = -
28	PB8
29	PB14
30	PB13
31	PB6
32	GND
33	VDDIO
34	PB5
35	PB15
36	PB17
37	VDDCORE
38	PB7
39	PB12
40	PB0
41	PB1
42	PB2
43	PB3
44	PB10
45	PB11
46	PA19/PGMD7
47	PA20/PGMD8
48	VDDIO
49	PA21/PGMD9
50	PA22/PGMD10

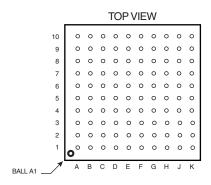
51	TDI
52	GND
53	PB16
54	PB4
55	PA23/PGMD11
56	PA24/PGMD12
57	NRST
58	TST
59	PA25/PGMD13
60	PA26/PGMD14
61	VDDIO
62	VDDCORE
63	PB18
64	PB19
65	PB20
66	PB21
67	PB22
68	GND
69	PB23
70	PB24
71	PB25
72	PB26
73	PA27/PGMD15
74	PA28
75	PA29

76	TDO
77	JTAGSEL
78	TMS
79	TCK
80	PA30
81	PA0/PGMEN0
82	PA1/PGMEN1
83	GND
84	VDDIO
85	PA3
86	PA2
87	VDDCORE
88	PA4/PGMNCMD
89	PA5/PGMRDY
90	PA6/PGMNOE
91	PA7/PGMNVALID
92	ERASE
93	DDM
94	DDP
95	VDDFLASH
96	GND
97	XIN/PGMCK
98	XOUT
99	PLLRC
100	VDDPLL

4.3 100-ball TFBGA Package Outline

Figure 4-2 shows the orientation of the 100-ball TFBGA package. A detailed mechanical description is given in the Mechanical Characteristics section of the full datasheet.

Figure 4-2. 100-ball TFBGA Package Orientation (Top View)



4.4 **100-ball TFBGA Pinout**

Table 4-2. Pinout in 100-ball TFBGA Package

Pin	Signal Name
A1	PA22/PGMD10
A2	PA21/PGMD9
А3	PA20/PGMD8
A4	PB1
A5	PB7
A6	PB5
A7	PB8
A8	PB9
A9	PA18/PGMD6
A10	VDDIO
B1	TDI
B2	PA19/PGMD7
В3	PB11
B4	PB2
B5	PB12
B6	PB15
B7	PB14
B8	PA14/PGMD2
B9	PA16/PGMD4
B10	PA17/PGMD5
C1	PB16
C2	PB4
C3	PB10
C4	PB3
C5	PB0

	•
Pin	Signal Name
C6	PB17
C7	PB13
C8	PA13/PGMD1
C9	PA12/PGMD0
C10	PA15/PGMD3
D1	PA23/PGMD11
D2	PA24/PGMD12
D3	NRST
D4	TST
D5	PB19
D6	PB6
D7	PA10/PGMM2
D8	VDDIO
D9	PB27/AD0
D10	PA11/PGMM3
E1	PA25/PGMD13
E2	PA26/PGMD14
E3	PB18
E4	PB20
E5	TMS
E6	GND
E7	VDDIO
E8	PB28/AD1
E9	VDDIO
E10	GND

Pin	Signal Name
F1	PB21
F2	PB23
F3	PB25
F4	PB26
F5	TCK
F6	PA6/PGMNOE
F7	ERASE
F8	VDDCORE
F9	GND
F10	VDDIN
G1	PB22
G2	PB24
G3	PA27/PGMD15
G4	TDO
G5	PA2
G6	PA5/PGMRDY
G7	VDDCORE
G8	GND
G9	PB30/AD3
G10	VDDOUT
H1	VDDCORE
H2	PA28
НЗ	JTAGSEL
H4	PA3
H5	PA4/PGMNCMD

Pin	Signal Name
H6	PA7/PGMNVALID
H7	PA9/PGMM1
H8	PA8/PGMM0
H9	PB29/AD2
H10	PLLRC
J1	PA29
J2	PA30
J3	PA0/PGMEN0
J4	PA1/PGMEN1
J5	VDDFLASH
J6	GND
J7	XIN/PGMCK
J8	XOUT
J9	GND
J10	VDDPLL
K1	VDDCORE
K2	VDDCORE
K3	DDP
K4	DDM
K5	GND
K6	AD7
K7	AD6
K8	AD5
K9	AD4
K10	ADVREF





5. Power Considerations

5.1 Power Supplies

The AT91SAM7XC512/256/128 has six types of power supply pins and integrates a voltage regulator, allowing the device to be supplied with only one voltage. The six power supply pin types are:

- VDDIN pin. It powers the voltage regulator and the ADC; voltage ranges from 3.0V to 3.6V, 3.3V nominal. In order to decrease current consumption, if the voltage regulator and the ADC are not used, VDDIN, ADVREF,AD4, AD5, AD6 and AD7 should be connected to GND. In this case, VDDOUT should be left unconnected.
- VDDOUT pin. It is the output of the 1.8V voltage regulator.
- VDDIO pin. It powers the I/O lines; voltage ranges from 3.0V to 3.6V, 3.3V nominal.
- VDDFLASH pin. It powers the USB transceivers and a part of the Flash and is required for the Flash to operate correctly; voltage ranges from 3.0V to 3.6V, 3.3V nominal.
- VDDCORE pins. They power the logic of the device; voltage ranges from 1.65V to 1.95V,
 1.8V typical. It can be connected to the VDDOUT pin with decoupling capacitor. VDDCORE is required for the device, including its embedded Flash, to operate correctly.
- VDDPLL pin. It powers the oscillator and the PLL. It can be connected directly to the VDDOUT pin.

No separate ground pins are provided for the different power supplies. Only GND pins are provided and should be connected as shortly as possible to the system ground plane.

5.2 Power Consumption

The AT91SAM7XC512/256/128 has a static current of less than 60 μ A on VDDCORE at 25°C, including the RC oscillator, the voltage regulator and the power-on reset when the brownout detector is deactivated. Activating the brownout detector adds 28 μ A static current.

The dynamic power consumption on VDDCORE is less than 90 mA at full speed when running out of the Flash. Under the same conditions, the power consumption on VDDFLASH does not exceed 10 mA.

5.3 Voltage Regulator

The AT91SAM7XC512/256/128 embeds a voltage regulator that is managed by the System Controller.

In Normal Mode, the voltage regulator consumes less than 100 μA static current and draws 100 mA of output current.

The voltage regulator also has a Low-power Mode. In this mode, it consumes less than 25 μ A static current and draws 1 mA of output current.

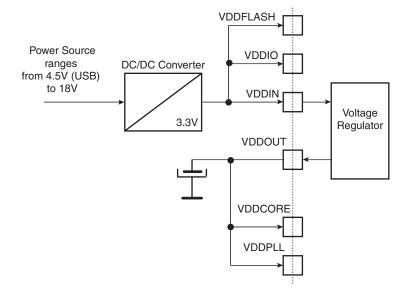
Adequate output supply decoupling is mandatory for VDDOUT to reduce ripple and avoid oscillations. The best way to achieve this is to use two capacitors in parallel: one external 470 pF (or 1 nF) NPO capacitor should be connected between VDDOUT and GND as close to the chip as possible. One external 2.2 μ F (or 3.3 μ F) X7R capacitor should be connected between VDDOUT and GND.

Adequate input supply decoupling is mandatory for VDDIN in order to improve startup stability and reduce source voltage drop. The input decoupling capacitor should be placed close to the chip. For example, two capacitors can be used in parallel: 100 nF NPO and $4.7 \, \mu F$ X7R.

5.4 Typical Powering Schematics

The AT91SAM7XC512/256/128 supports a 3.3V single supply mode. The internal regulator input connected to the 3.3V source and its output feeds VDDCORE and the VDDPLL. Figure 5-1 shows the power schematics to be used for USB bus-powered systems.

Figure 5-1. 3.3V System Single Power Supply Schematic







6. I/O Lines Considerations

6.1 JTAG Port Pins

TMS, TDI and TCK are schmitt trigger inputs and are not 5-V tolerant. TMS, TDI and TCK do not integrate a pull-up resistor.

TDO is an output, driven at up to VDDIO, and has no pull-up resistor.

The JTAGSEL pin is used to select the JTAG boundary scan when asserted at a high level. The JTAGSEL pin integrates a permanent pull-down resistor of about 15 k Ω

To eliminate any risk of spuriously entering the JTAG boundary scan mode due to noise on JTAGSEL, it should be tied externally to GND if boundary scan is not used, or pulled down with an external low-value resistor (such as 1 $k\Omega$).

6.2 Test Pin

The TST pin is used for manufacturing test or fast programming mode of the AT91SAM7XC512/256/128 when asserted high. The TST pin integrates a permanent pull-down resistor of about 15 k Ω to GND.

To eliminate any risk of entering the test mode due to noise on the TST pin, it should be tied to GND if the FFPI is not used, or pulled down with an external low-value resistor (such as $1 \text{ k}\Omega$).

To enter fast programming mode, the TST pin and the PA0 and PA1 pins should be tied high and PA2 tied to low.

Driving the TST pin at a high level while PA0 or PA1 is driven at 0 leads to unpredictable results.

6.3 Reset Pin

The NRST pin is bidirectional with an open drain output buffer. It is handled by the on-chip reset controller and can be driven low to provide a reset signal to the external components or asserted low externally to reset the microcontroller. There is no constraint on the length of the reset pulse, and the reset controller can guarantee a minimum pulse length. This allows connection of a simple push-button on the NRST pin as system user reset, and the use of the signal NRST to reset all the components of the system.

The NRST pin integrates a permanent pull-up resistor to VDDIO.

6.4 ERASE Pin

The ERASE pin is used to re-initialize the Flash content and some of its NVM bits. It integrates a permanent pull-down resistor of about 15 k Ω to GND.

To eliminate any risk of erasing the Flash due to noise on the ERASE pin, it shoul be tied externally to GND, which prevents erasing the Flash from the application, or pulled down with an external low-value resistor (such as 1 $k\Omega$).

This pin is debounced by the RC oscillator to improve the glitch tolerance. Minimum debouncing time is 200 ms.

6.5 PIO Controller Lines

All the I/O lines, PA0 to PA30 and PB0 to PB30, are 5V-tolerant and all integrate a programmable pull-up resistor. Programming of this pull-up resistor is performed independently for each I/O line through the PIO controllers.

AT91SAM7XC512/256/128

5V-tolerant means that the I/O lines can drive voltage level according to VDDIO, but can be driven with a voltage of up to 5.5V. However, driving an I/O line with a voltage over VDDIO while the programmable pull-up resistor is enabled will create a current path through the pull-up resistor from the I/O line to VDDIO. Care should be taken, in particular at reset, as all the I/O lines default to input with pull-up resistor enabled at reset.

6.6 I/O Lines Current Drawing

The PIO lines PA0 to PA3 are high-drive current capable. Each of these I/O lines can drive up to 16 mA permanently.

The remaining I/O lines can draw only 8 mA.

However, the total current drawn by all the I/O lines cannot exceed 200 mA.





7. Processor and Architecture

7.1 ARM7TDMI Processor

- RISC processor based on ARMv4T Von Neumann architecture
 - Runs at up to 55 MHz, providing 0.9 MIPS/MHz
- Two instruction sets
 - ARM® high-performance 32-bit instruction set
 - Thumb® high code density 16-bit instruction set
- Three-stage pipeline architecture
 - Instruction Fetch (F)
 - Instruction Decode (D)
 - Execute (E)

7.2 Debug and Test Features

- Integrated embedded in-circuit emulator
 - Two watchpoint units
 - Test access port accessible through a JTAG protocol
 - Debug communication channel
- Debug Unit
 - Two-pin UART
 - Debug communication channel interrupt handling
 - Chip ID Register
- IEEE1149.1 JTAG Boundary-scan on all digital pins

7.3 Memory Controller

- Programmable Bus Arbiter
 - Handles requests from the ARM7TDMI, the Ethernet MAC and the Peripheral DMA Controller
- Address decoder provides selection signals for
 - Three internal 1 Mbyte memory areas
 - One 256 Mbyte embedded peripheral area
- · Abort Status Registers
 - Source, Type and all parameters of the access leading to an abort are saved
 - Facilitates debug by detection of bad pointers
- Misalignment Detector
 - Alignment checking of all data accesses
 - Abort generation in case of misalignment
- Remap Command
 - Remaps the SRAM in place of the embedded non-volatile memory
 - Allows handling of dynamic exception vectors

- Embedded Flash Controller
 - Embedded Flash interface, up to three programmable wait states
 - Prefetch buffer, buffering and anticipating the 16-bit requests, reducing the required wait states
 - Key-protected program, erase and lock/unlock sequencer
 - Single command for erasing, programming and locking operations
 - Interrupt generation in case of forbidden operation

7.4 Peripheral DMA Controller

- Handles data transfer between peripherals and memories
- Seventeen channels
 - Two for each USART
 - Two for the Debug Unit
 - Two for the Serial Synchronous Controller
 - Two for each Serial Peripheral Interface
 - Two for the Advanced Encryption Standard 128-bit accelerator
 - Two for the Triple Data Encryption Standard 128-bit accelerator
 - One for the Analog-to-digital Converter
- · Low bus arbitration overhead
 - One Master Clock cycle needed for a transfer from memory to peripheral
 - Two Master Clock cycles needed for a transfer from peripheral to memory
- Next Pointer management for reducing interrupt latency requirements





8. Memory

8.1 AT91SAM7XC512

- 512 Kbytes of dual-plane Flash Memory
 - 2 contiguous banks of 1024 pages of 256 bytes
 - Fast access time, 30 MHz single-cycle access in Worst Case conditions
 - Page programming time: 6 ms, including page auto-erase
 - Page programming without auto-erase: 3 ms
 - Full chip erase time: 15 ms
 - 10,000 write cycles, 10-year data retention capability
 - 32 lock bits, protecting 32 sectors of 64 pages
 - Protection Mode to secure contents of the Flash
- 128 Kbytes of Fast SRAM
 - Single-cycle access at full speed

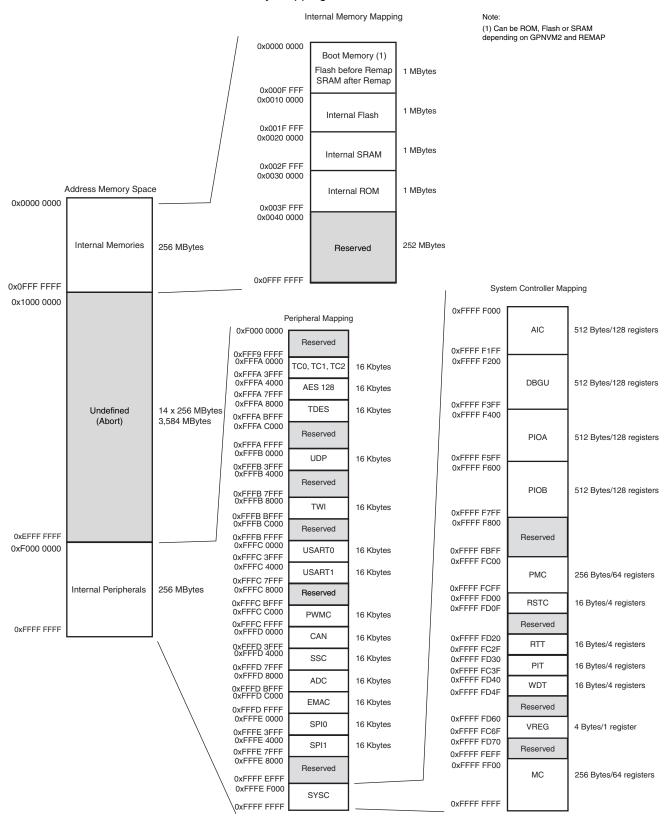
8.2 AT91SAM7XC256

- 256 Kbytes of Flash Memory
 - 1024 pages of 256 bytes
 - Fast access time, 30 MHz single-cycle access in Worst Case conditions
 - Page programming time: 6 ms, including page auto-erase
 - Page programming without auto-erase: 3 ms
 - Full chip erase time: 15 ms
 - 10,000 write cycles, 10-year data retention capability
 - 16 lock bits, each protecting 16 sectors of 64 pages
 - Protection Mode to secure contents of the Flash
- 64 Kbytes of Fast SRAM
 - Single-cycle access at full speed

8.3 AT91SAM7XC128

- 128 Kbytes of Flash Memory
 - 512 pages of 256 bytes
 - Fast access time, 30 MHz single-cycle access in Worst Case conditions
 - Page programming time: 6 ms, including page auto-erase
 - Page programming without auto-erase: 3 ms
 - Full chip erase time: 15 ms
 - 10,000 write cycles, 10-year data retention capability
 - 8 lock bits, each protecting 8 sectors of 64 pages
 - Protection Mode to secure contents of the Flash
- 32 Kbytes of Fast SRAM
 - Single-cycle access at full speed

Figure 8-1. AT91SAM7XC512/256/128 Memory Mapping







8.4 Memory Mapping

8.4.1 Internal RAM

- The AT91SAM7XC512 embeds a high-speed 128-Kbyte SRAM bank.
- The AT91SAM7XC256 embeds a high-speed 64-Kbyte SRAM bank.
- The AT91SAM7XC128 embeds a high-speed 32-Kbyte SRAM bank.

After reset and until the Remap Command is performed, the SRAM is only accessible at address 0x0020 0000. After Remap, the SRAM also becomes available at address 0x0.

8.4.2 Internal ROM

The AT91SAM7XC512/256/128 embeds an Internal ROM. At any time, the ROM is mapped at address 0x30 0000. The ROM contains the FFPI and the SAM-BA program.

8.4.3 Internal Flash

- The AT91SAM7XC512 features two banks (dual plane) of 256 Kbytes of Flash.
- The AT91SAM7XC256 features one bank (single plane) of 256 Kbytes of Flash.
- The AT91SAM7XC128 features one bank (single plane) of 128 Kbytes of Flash.

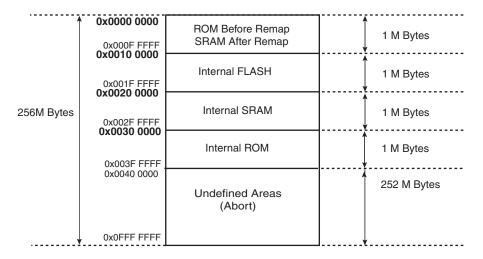
At any time, the Flash is mapped to address 0x0010 0000. It is also accessible at address 0x0 after the reset, if GPNVM bit 2 is set and before the Remap Command.

A general purpose NVM (GPNVM) bit is used to boot either on the ROM (default) or from the Flash.

This GPNVM bit can be cleared or set respectively through the commands "Clear General-purpose NVM Bit" and "Set General-purpose NVM Bit" of the EFC User Interface.

Setting the GPNVM Bit 2 selects the boot from the Flash. Asserting ERASE clears the GPNVM Bit 2 and thus selects the boot from the ROM by default.

Figure 8-2. Internal Memory Mapping with GPNVM Bit 2 = 0 (default)



0x0000 0000 Flash Before Remap 1 M Bytes SRAM After Remap 0x000F FFFF 0x0010 0000 Internal FLASH 1 M Bytes 0x001F FFFF 0x0020 0000 Internal SRAM 256M Bytes 1 M Bytes 0x002F FFFF 0x0030 0000 Internal ROM 1 M Bytes 0x003F FFFF 0x0040 0000 252 M Bytes **Undefined Areas** (Abort) 0x0FFF FFFF

Figure 8-3. Internal Memory Mapping with GPNVM Bit 2 = 1

8.5 Embedded Flash

8.5.1 Flash Overview

- The Flash of the AT91SAM7XC512 is organized in two banks (dual plane) 0f 1254 pages of 256 bytes. The 524, 288 bytes are organized in 32-bit words.
- The Flash of the AT91SAM7XC256 is organized in 1024 pages of 256 bytes (single plane). It reads as 65,536 32-bit words.
- The Flash of the AT91SAM7XC128 is organized in 512 pages of 256 bytes (single plane). It reads as 32,768 32-bit words.

The Flash contains a 256-byte write buffer, accessible through a 32-bit interface.

The Flash benefits from the integration of a power reset cell and from the brownout detector. This prevents code corruption during power supply changes, even in the worst conditions.

When Flash is not used (read or write access), it is automatically placed into standby mode.

8.5.2 Embedded Flash Controller

The Embedded Flash Controller (EFC) manages accesses performed by the masters of the system. It enables reading the Flash and writing the write buffer. It also contains a User Interface, mapped within the Memory Controller on the APB. The User Interface allows:

- programming of the access parameters of the Flash (number of wait states, timings, etc.)
- starting commands such as full erase, page erase, page program, NVM bit set, NVM bit clear, etc.
- · getting the end status of the last command
- · getting error status
- programming interrupts on the end of the last commands or on errors

The Embedded Flash Controller also provides a dual 32-bit Prefetch Buffer that optimizes 16-bit access to the Flash. This is particularly efficient when the processor is running in Thumb mode.

Two EFCs are embedded in the AT91SAM7XC512 to control each bank of 256 KBytes. Dualplane organization allows concurrent read and program functionality. Read from one memory





plane may be performed even while program or erase functions are being executed in the other memory plane.

One EFC is embedded in the AT91SAM7XC256/128 to control the single plane of 256/128 KBytes.

8.5.3 Lock Regions

8.5.3.1 AT91SAM7XC512

Two Embedded Flash Controllers each manage 16 lock bits to protect 16 regions of the flash against inadvertent flash erasing or programming commands. The AT91SAM7XC512 contains 32 lock regions and each lock region contains 64 pages of 256 bytes. Each lock region has a size of 16 Kbytes.

If a locked-region's erase or program command occurs, the command is aborted and the EFC trigs an interrupt.

The 32 NVM bits are software programmable through both of the EFC User Interfaces. The command "Set Lock Bit" enables the protection. The command "Clear Lock Bit" unlocks the lock region.

Asserting the ERASE pin clears the lock bits, thus unlocking the entire Flash.

8.5.3.2 AT91SAM7XC256

The Embedded Flash Controller manages 16 lock bits to protect 16 regions of the flash against inadvertent flash erasing or programming commands. The AT91SAM7XC256 contains 16 lock regions and each lock region contains 64 pages of 256 bytes. Each lock region has a size of 16 Kbytes.

If a locked-region's erase or program command occurs, the command is aborted and the EFC trigs an interrupt.

The 16 NVM bits are software programmable through the EFC User Interface. The command "Set Lock Bit" enables the protection. The command "Clear Lock Bit" unlocks the lock region.

Asserting the ERASE pin clears the lock bits, thus unlocking the entire Flash.

8.5.3.3 AT91SAM7XC128

The Embedded Flash Controller manages 8 lock bits to protect 8 regions of the flash against inadvertent flash erasing or programming commands. The AT91SAM7XC128 contains 8 lock regions and each lock region contains 64 pages of 256 bytes. Each lock region has a size of 16 Kbytes.

If a locked-region's erase or program command occurs, the command is aborted and the EFC trigs an interrupt.

The 8 NVM bits are software programmable through the EFC User Interface. The command "Set Lock Bit" enables the protection. The command "Clear Lock Bit" unlocks the lock region.

Asserting the ERASE pin clears the lock bits, thus unlocking the entire Flash.

8.5.4 Security Bit Feature

The AT91SAM7XC512/256/128 features a security bit, based on a specific NVM-Bit. When the security is enabled, any access to the Flash, either through the ICE interface or through the Fast

Flash Programming Interface, is forbidden. This ensures the confidentiality of the code programmed in the Flash.

This security bit can only be enabled, through the Command "Set Security Bit" of the EFC User Interface. Disabling the security bit can only be achieved by asserting the ERASE pin at 1, and after a full flash erase is performed. When the security bit is deactivated, all accesses to the flash are permitted.

It is important to note that the assertion of the ERASE pin should always be longer than 220 ms.

As the ERASE pin integrates a permanent pull-down, it can be left unconnected during normal operation. However, it is safer to connect it directly to GND for the final application.

8.5.5 Non-volatile Brownout Detector Control

Two general purpose NVM (GPNVM) bits are used for controlling the brownout detector (BOD), so that even after a power loss, the brownout detector operations remain in their state.

These two GPNVM bits can be cleared or set respectively through the commands "Clear General-purpose NVM Bit" and "Set General-purpose NVM Bit" of the EFC User Interface.

- GPNVM Bit 0 is used as a brownout detector enable bit. Setting the GPNVM Bit 0 enables
 the BOD, clearing it disables the BOD. Asserting ERASE clears the GPNVM Bit 0 and thus
 disables the brownout detector by default.
- The GPNVM Bit 1 is used as a brownout reset enable signal for the reset controller. Setting
 the GPNVM Bit 1 enables the brownout reset when a brownout is detected, Clearing the
 GPNVM Bit 1 disables the brownout reset. Asserting ERASE disables the brownout reset by
 default.

8.5.6 Calibration Bits

Eight NVM bits are used to calibrate the brownout detector and the voltage regulator. These bits are factory configured and cannot be changed by the user. The ERASE pin has no effect on the calibration bits.

8.6 Fast Flash Programming Interface

The Fast Flash Programming Interface allows programming the device through either a serial JTAG interface or through a multiplexed fully-handshaked parallel port. It allows gang-programming with market-standard industrial programmers.

The FFPI supports read, page program, page erase, full erase, lock, unlock and protect commands.

The Fast Flash Programming Interface is enabled and the Fast Programming Mode is entered when the TST pin and the PA0 and PA1 pins are all tied high.

8.7 SAM-BA Boot Assistant

The SAM-BA Boot Assistant is a default Boot Program that provides an easy way to program insitu the on-chip Flash memory.

The SAM-BA Boot Assistant supports serial communication via the DBGU or the USB Device Port.

 Communication via the DBGU supports a wide range of crystals from 3 to 20 MHz via software auto-detection.





• Communication via the USB Device Port is limited to an 18.432 MHz crystal.

The SAM-BA Boot provides an interface with SAM-BA Graphic User Interface (GUI).

The SAM-BA Boot is in ROM and is mapped at address 0x0 when the GPNVM Bit 2 is set to 0.

When GPNVM bit 2 is set to 1, the device boots from the Flash.

When GPNVM bit 2 is set to 0, the device boots from ROM (SAM-BA).

9. System Controller

The System Controller manages all vital blocks of the microcontroller: interrupts, clocks, power, time, debug and reset.

The System Controller peripherals are all mapped to the highest 4 Kbytes of address space, between addresses 0xFFFF F000 and 0xFFFF FFFF.

Figure 9-1 on page 26 shows the System Controller Block Diagram.

Figure 8-1 on page 19 shows the mapping of the User Interface of the System Controller peripherals. Note that the Memory Controller configuration user interface is also mapped within this address space.

